## NSN 5961-01-163-7845

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Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-163-7845 **Inclosure Material:** Plastic **Overall Length:** 0.650 inches **Terminal Length:** 0.500 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **Mounting Facility Quantity:** Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220ab **Mounting Method:** Unthreaded hole **Terminal Circle Diameter:** 0.210 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 400.0 repetitive peak off-state voltage and 10.0 peak gate voltage **Current Rating Per Characteristic:** 8.00 amperes forward current, total rms horsepower metric and 100.00 amperes peak forward surge current absolute **Power Rating Per Characteristic:** 20.0 watts small-signal input power, common-collector blank and 0.5 watts small-signal input power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 3 pin **Specification Data:** 80131-release6376 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: